

SSCN144EGS6

NPN Type Digital Transistor (built-in resistors)

Features

vcc	VIN	Ю	R1	R2/R1 Typ.
50V	-10~+40V	30mA	47ΚΩ	1

Description

Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).

The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects. Only the on/off conditions need to be set for operation, making the device design easy.

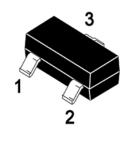
Applications

- Amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance

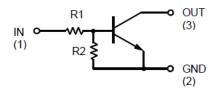
Ordering Information

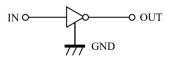
Device	Package	Shipping
SSCN144EGS6	SOT-23	3000/Reel

Pin configuration

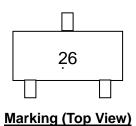


SOT-23





Circuit Diagram





➤ Absolute Maximum Ratings(T_A=25°C unless otherwise noted)

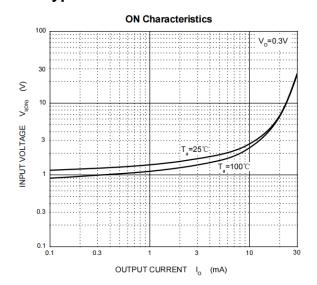
Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	50	V
Input Voltage	V _{CN}	-10 to +40	V
Output current	I _O	30	mA
Power Dissipation	P _D	200	mW
Junction Temperature	TJ	-55 to 150	$^{\circ}\!\mathbb{C}$
Storage Temperature	T _{STG}	-55 to 150	$^{\circ}\mathbb{C}$

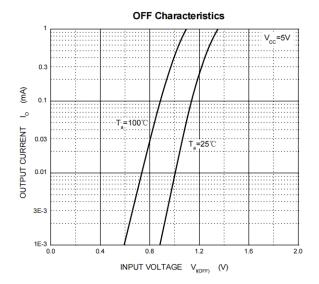
➤ Electrical Characteristics (T_A=25°C unless otherwise noted)

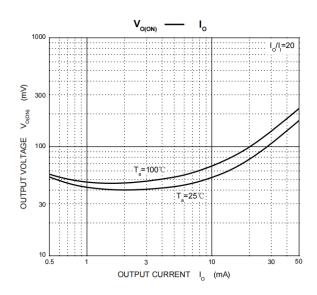
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Input Valtage	V _{I(off)}	Vcc = 5V, Io = 100uA	0.5			V
Input Voltage	V _{I(on)}	$V_{CC} = 0.3V$, $I_0 = 2mA$			3	V
Output Voltage	V _{O(on)}	I _O /I _I = 10mA/0. 5mA			0.3	V
Input Current	lı	V _I = 5V			0.18	mA
Output Current	I _{O(off)}	Vcc = 50V, Vı = 0V			0.5	uA
DC Current Gain	G ₁	V _O = 5V, I _O = 5mA	68			
Input Resistance	R ₁		32.9	47	61.1	ΚΩ
Resistance Ration	R ₂ /R ₁		0.8	1.0	1.2	
Transition Frequency	f⊤	V _{CE} =10V, I _E =-5mA, f=100MHz		250		MHz

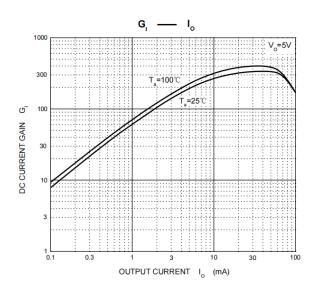


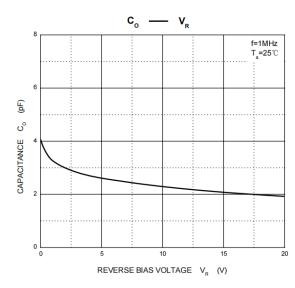
\succ Typical Performance Characteristics (T_A=25 $^{\circ}$ C unless otherwise noted)

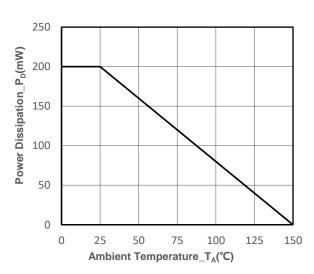










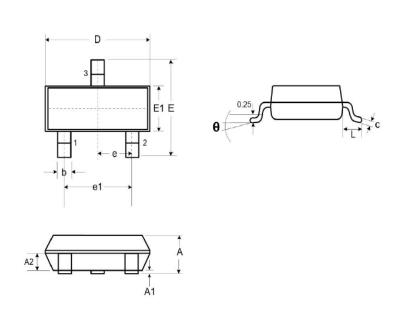




Package Information

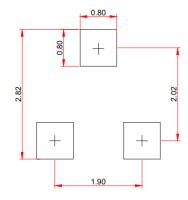
Mechanical Data

SOT-23



DIM	Millimeters				
DIM	Min.	Тур.	Max.		
Α	0.89	-	1.12		
A 1	0.01	-	0.10		
A2	0.88	0.95	1.02		
b	0.30	-	0.51		
С	0.08	-	0.18		
D	2.80	2.90	3.04		
Е	2.10	2.37	2.64		
E1	1.20	1.30	1.40		
е	0.95				
e1	1.90				
L	0.40	0.50	0.60		
L1	0.55				
N	3				
θ	0°	-	8°		

Recommended Pad outline (Unit: mm)





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